

PTO/SB/03A (08-05)

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**INFORMATION DISCLOSURE
STATEMENT BY APPLICANT**

(Use as many sheets as necessary)

Sheet 1

of 2

Complete if Known

Application Number	10/789,638
Filing Date	02/27/2004
First Named Inventor	Bender
Art Unit	1765
Examiner Name	Nadine G. Norton
Attorney Docket Number	Solx 4

U. S. PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Document Number Number-Kind Code ² (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
/G.N.R./		US 5,242,531	09/07/1993	Klingshirn et al.	Col. 4, L14-25ff
/G.N.R./		US 5,324,488	06/28/1994	Klingshirn et al.	Col. 5, L 24-54
/G.N.R./		US 5,437,242	08/01/1995	Hofstetter et al.	Col. 4, L 3-46
/G.N.R./		US 4,036,595	07/19/1977	Lorenzini et al.	Col. 2 L61-Col.3 L30
/G.N.R./		US 4,410,494	10/18/1983	Fiegl	Col. 4, L16ff
/G.N.R./		US 4,282,184	08/04/1981	Fiegl et al.	Col. 5, L11-68
/G.N.R./		US 4,396,824	08/02/1983	Fiegl et al.	Col. 5, L55ff
/G.N.R./		US 4,454,096	06/12/1984	Lorenzini et al.	Col. 3, L28ff
/G.N.R./		US 5,373,805	12/20/1994	Takano et al.	Col. 8, L13ff
/G.N.R./		US 5,733,368	03/31/1998	Nagai et al.	Col. 3, L37-55
/G.N.R./		US 5,876,496	03/02/1999	Nagai et al.	Col. 3, L 59-67ff
/G.N.R./		US 5,360,480	11/01/1994	Altekrueger	Col. 3, L4-59
/G.N.R./		US 4,592,895	06/03/1986	Matsutani et al.	Col. 5, L16-20ff
/G.N.R./		US 5,288,366	02/22/1994	Holder	Col. 3, L35-58
/G.N.R./		US 5,314,667	05/24/1994	Lim et al.	Col. 4, L1-25
/G.N.R./		US 4,265,859	05/05/1981	Jewett	Col. 3, L50-64
/G.N.R./		US 4,289,571	09/15/1981	Jewett	Col. 2 L64-Col.3L14
/G.N.R./		US 4,659,421	04/21/1987	Jewett	Col. 7 L54-Col.8 L65
/G.N.R./		US 5,427,056	06/27/1995	Imai et al.	Col. 5, L18-Col.6 L2

FOREIGN PATENT DOCUMENTS

Examiner Initials*	Cite No. ¹	Foreign Patent Document Country Code ³ Number ⁴ Kind Code ⁵ (if known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages Or Relevant Figures Appear	T ⁶

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/G. Nagesh Rao/ (02/26/2008)

Date
Considered

02/26/2008

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PTQ/SB/02A (08-03)

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Substitute for H.R. 1449/PTQ

INFORMATION DISCLOSURE STATEMENT BY APPLICANT

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Sheet 2 of 2

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Application Number	10/789,638
Filing Date	2/27/2004
First Named Inventor	Bender
Art Unit	1765
Examiner Name	Nadine G. Norton
Attorney Docket Number	Solx 4

U. S. PATENT DOCUMENTS

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FOREIGN PATENT DOCUMENTS

[illegible]

Examiner	/G. Nagesh Rao/ (02/26/2008)
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Date Considered	02/26/2008
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PTO/SB/058 (08-C3)

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**INFORMATION DISCLOSURE
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Complete if Known

Application Number	10/789.638
Filing Date	02/27/2004
First Named Inventor	Bender
Art Unit	1765
Examiner Name	Nadine G. Norton
Attorney Docket Number	Solx 4

Sheet 1 of 1

NON PATENT LITERATURE DOCUMENTS

Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.	T ²
/G.N.R./		C. WANG et al.; A continuous Czochralski silicon crystal growth system; Journal of Crystal Growth 250 (2003), pgs. 209-214	✓
/G.N.R./		T. WANGM; Shallow Melt Czochralski Growth of Semiconductor Silicon; NREL Golden, CO, May 8, 2003.	✓
/G.N.R./		HOPKINS et al.; Crystal Growth Considerations in the Use of "Solar Grade" Silicon; Journal of Crystal Growth 42 (1977) 493-498	✓
/G.N.R./		M.H. LEIPOLD et al.; Materials of Construction for Silicon Crystal Growth; Journal of Crystal Growth 50 (1980) 366-377	✓

Examiner
Signature

/G. Nagesh Rao/ (02/26/2008)

Date
Considered

02/26/2008

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